

Medium Power Phase Control Thyristors (Stud Version), 50 A



TO-208AC (TO-65)

FEATURES

- High current rating
- Excellent dynamic characteristics
- $dV/dt = 1000 \text{ V}/\mu\text{s}$ option
- Superior surge capabilities
- Standard package
- Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

PRODUCT SUMMARY	
Package	TO-208AC (TO-65)
Diode variation	Single SCR
$I_{T(AV)}$	50 A
V_{DRM}/V_{RRM}	100 V to 1200 V
V_{TM}	1.60 V
I_{GT}	100 mA
T_J	-40 °C to 125 °C

TYPICAL APPLICATIONS

- Phase control applications in converters
- Lighting circuits
- Battery charges
- Regulated power supplies and temperature and speed control circuit
- Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		50	A
	T_C	94	°C
$I_{T(RMS)}$		80	A
I_{TSM}	50 Hz	1430	A
	60 Hz	1490	
I^2t	50 Hz	10.18	kA ² s
	60 Hz	9.30	
V_{DRM}/V_{RRM}		100 to 1200	V
t_q	Typical	110	μs
T_J		-40 to 125	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-50RIA	10	100	150	15
	20	200	300	
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dI/dt does not exceed 20 A/ μs

⁽²⁾ For voltage pulses with $t_p \leq 5 \text{ ms}$



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current at case temperature	$I_{T(AV)}$	180° sinusoidal conduction		50	A
				94	°C
Maximum RMS on-state current	$I_{T(RMS)}$			80	A
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	t = 10 ms	No voltage reappplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	A
		t = 8.3 ms			
		t = 10 ms	100 % V_{RRM} reappplied		
		t = 8.3 ms			
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied		kA ² s
		t = 8.3 ms			
		t = 10 ms	100 % V_{RRM} reappplied		
		t = 8.3 ms			
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied, $T_J = T_J$ maximum		101.8	kA ² √s
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		0.94	V
High level value of threshold voltage	$V_{T(TO)2}$	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		1.08	
Low level value of on-state slope resistance	r_{t1}	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		4.08	mΩ
High level value of on-state slope resistance	r_{t2}	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		3.34	
Maximum on-state voltage	V_{TM}	$I_{pk} = 157$ A, $T_J = 25$ °C		1.60	V
Maximum holding current	I_H	$T_J = 25$ °C, anode supply 22 V, resistive load, initial $I_T = 2$ A		200	mA
Latching current	I_L	Anode supply 6 V, resistive load		400	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum rate of rise of turned-on current	dI/dt	$T_C = 125$ °C, $V_{DM} = \text{Rated } V_{DRM}$, Gate pulse = 20 V, 15 Ω, $t_p = 6$ μs, $t_r = 0.1$ μs maximum $I_{TM} = (2 \times \text{rated } dI/dt)$ A		200	A/μs
				$V_{DRM} \leq 600$ V	
Typical delay time	t_d	$T_C = 25$ °C, $V_{DM} = \text{Rated } V_{DRM}$, $I_{TM} = 10$ A dc resistive circuit Gate pulse = 10 V, 15 Ω source, $t_p = 20$ μs		0.9	μs
Typical turn-off time	t_q	$T_C = 125$ °C, $I_{TM} = 50$ A, reappplied $dV/dt = 20$ V/μs $dI_r/dt = -10$ A/μs, $V_R = 50$ V		110	

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}		200	V/μs
		$T_J = T_J$ maximum linear to 67 % rated V_{DRM}		500 ⁽¹⁾	

Note

⁽¹⁾ Available with $dV/dt = 1000$ V/μs, to complete code add S90 i.e. 50RIA120S90



TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P_{GM}	$T_J = T_J$ maximum, $t_p \leq 5$ ms		10	W
Maximum average gate power	$P_{G(AV)}$			2.5	
Maximum peak positive gate current	I_{GM}			2.5	A
Maximum peak positive gate voltage	$+V_{GM}$			20	V
Maximum peak negative gate voltage	$-V_{GM}$			10	
DC gate current required to trigger	I_{GT}	$T_J = -40$ °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	250	mA
		$T_J = 25$ °C		100	
		$T_J = 125$ °C		50	
DC gate voltage required to trigger	V_{GT}	$T_J = -40$ °C		3.5	V
		$T_J = 25$ °C		2.5	
DC gate current not to trigger	I_{GD}	$T_J = T_J$ maximum, $V_{DRM} =$ Rated voltage		Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V_{DRM} anode to cathode applied	5.0
DC gate voltage not to trigger	V_{GD}	$T_J = T_J$ maximum	0.2		V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum operating junction and storage temperature range	T_J, T_{Stg}			-40 to 125	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		0.35	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased		0.25	
Allowable mounting torque		Non-lubricated threads		3.4^{+0-10} % (30)	N · m (lbf · in)
		Lubricated threads		2.3^{+0-10} % (20)	
Approximate weight				28	g
				1.0	oz.
Case style		See dimensions - link at the end of datasheet		TO-208AC (TO-65)	

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.078	0.057	$T_J = T_J$ maximum	K/W
120°	0.094	0.098		
90°	0.120	0.130		
60°	0.176	0.183		
30°	0.294	0.296		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



Fig. 1 - Current Ratings Characteristics

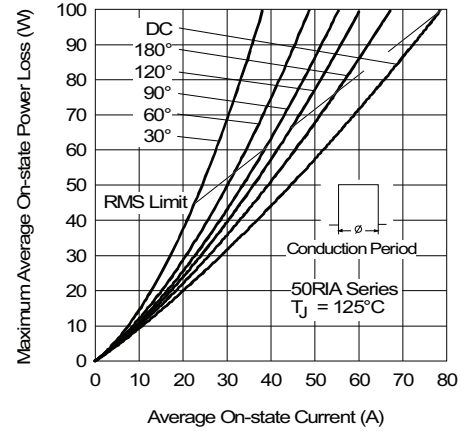


Fig. 4 - On-State Power Loss Characteristics



Fig. 2 - Current Ratings Characteristics



Fig. 5 - Maximum Non-Repetitive Surge Current

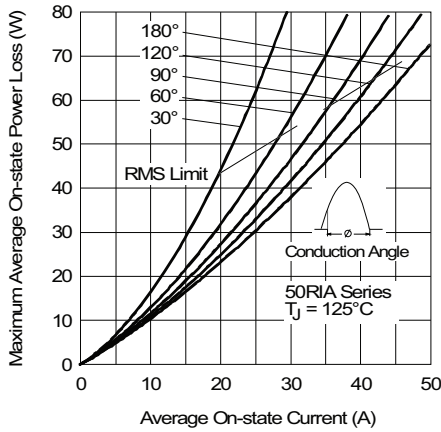


Fig. 3 - On-State Power Loss Characteristics



Fig. 6 - Maximum Non-Repetitive Surge Current



Fig. 7 - Forward Voltage Drop Characteristics

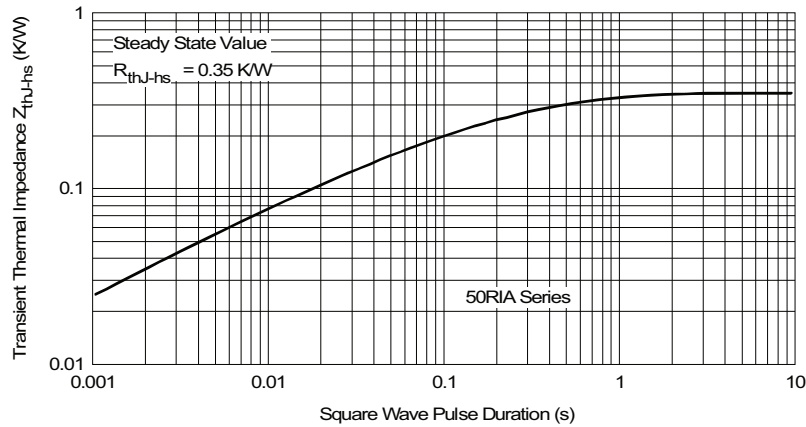


Fig. 8 - Thermal Impedance Z_{thJc} Characteristics

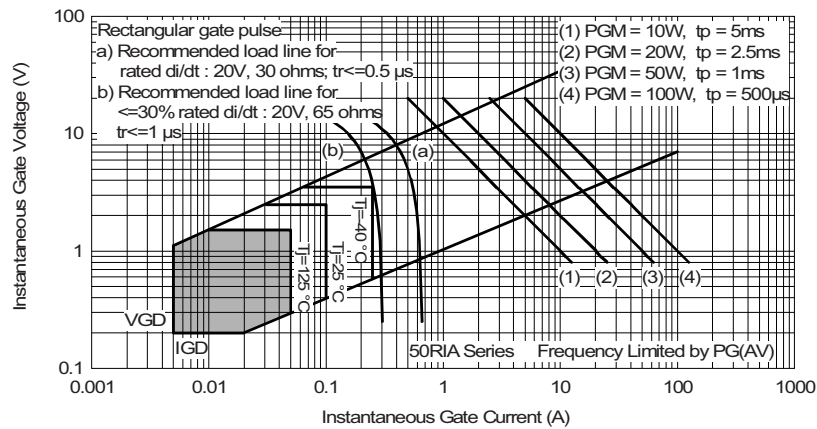


Fig. 9 - Gate Characteristics



ORDERING INFORMATION TABLE

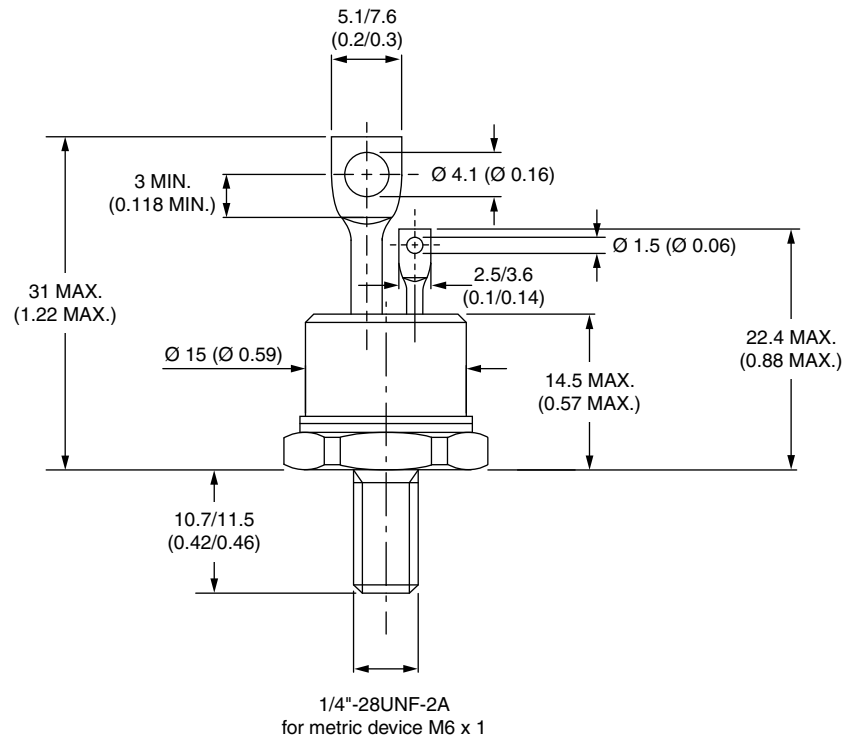


- 1** - Vishay Semiconductors product
- 2** - Current code
- 3** - Essential part number
- 4** - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 5** - Critical dV/dt:
 - None = 500 V/μs (standard value)
 - S90 = 1000 V/μs (special selection)
- 6** -
 - None = Stud base TO-208AC (TO-65) 1/4" 28UNF-2A
 - M = Stud base TO-208AC (TO-65) M6 x 1

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95334

TO-208AC (TO-65)

DIMENSIONS in millimeters (inches)





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